

28/1  
J.W.IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Munir H. Nayfeh  
 Serial No.: 09/496,506  
 Conf. No.: 6344  
 Filed: February 2, 2000  
 For: SILICON NANOPARTICLE FIELD  
 EFFECT TRANSISTOR AND  
 TRANSISTOR MEMORY DEVICE  
 Art Unit: 2811  
 Examiner: Sara W. Crane

I hereby certify that this paper is being deposited with the  
 United States Postal Service as FIRST-CLASS mail in an  
 envelope addressed to: Mail Stop AMENDMENT,  
 Commissioner for Patents, P.O. Box 1450, Alexandria, VA  
 22313-1450, on this date.

December 29, 2004

Date  
F-CLASS.WCM

Appr. February 20, 1998

Registration No. 43,874

Attorney for Applicant

Mail Stop AMENDMENT  
 Commissioner for Patents  
 P.O. Box 1450  
 Alexandria, VA 22313-1450

TRANSMITTAL

Dear Sir:

Enclosed please find the following:

(X) Response H.

(X) Declaration of Munir Nayfeh.

(X) Petition for Extension of Time (in duplicate), with a check in the amount of \$510.00.

(X) If a Petition under 37 C.F.R. §1.136(a) for an extension of time for response is required to make the attached response timely and does not separately accompany this transmittal, Applicant(s) hereby petition(s) under 37 C.F.R. §1.136(a) for an extension of time for response in the above-identified application for the period required to make the attached response timely.

(X) The Commissioner is hereby authorized to charge any additional fees which may be required to this application under 37 C.F.R. §§1.16-1.17, or credit any overpayment, to Deposit Account No. 07-2069. A duplicate copy of this sheet is enclosed.

Customer No. 24978

December 29, 2004

300 South Wacker Drive - Suite 2500  
 Chicago, Illinois 60606  
 Tel: (312) 360-0080  
 Fax: (312) 360-9315  
 P:\DOCS\1201\63407\795738.DOC

Respectfully submitted,

GREER, BURNS &amp; CRAIN, LTD.

By: Arik B. Ranson  
 Arik B. Ranson  
 Registration No. 43,874

1201.63407



PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Munir H. Nayfeh

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Registration No. 43,874

Attorney for Applicant

RESPONSE H

Mail Stop AMENDMENT  
Commissioner of Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir:

In response to the Office Action mailed June 29, 2004, please consider the following remarks: